NSN 5961-00-936-5788 Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.250 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.335 inches
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
60.0 collector to base voltage, dc all transistor and 30.0 collector to emitter voltage, dc all transistor and 7.0 emitter to base voltage, dc all
transistor
Power Rating Per Characteristic:
60.0 watts small-signal input power, common-collector preset all transistor
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
All transistor junction pattern arrangement: npn
Terminal Type And Quantity:
6 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0